SONY

Ver.2.0

IMX462LQR

Diagonal 6.46 mm (Type 1/2.8) CMOS Solid-state Image Sensor with Square Pixel for Color Cameras

Description

The IMX462LQR is a diagonal 6.46 mm (Type 1/2.8) CMOS active pixel type solid-state image sensor with a square pixel array and 2.13 M effective pixels. This chip operates with analog 2.9 V, digital 1.2 V, and interface 1.8 V triple power supply, and has low power consumption. High sensitivity, low dark current and no smear are achieved through the adoption of R, G and B primary color mosaic filters. This chip features an electronic shutter with variable charge-integration time.

(Applications: Surveillance cameras, FA cameras, Industrial cameras)

Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Input frequency: 74.25 MHz / 37.125 MHz
- ◆ Number of recommended recording pixels: 1920 (H) × 1080 (V) approx. 2.07 M pixels
- ◆ Readout mode

All-pixel scan mode

720p-HD readout mode

Window cropping mode

Vertical / Horizontal direction-normal / inverted readout mode

- ◆ Readout rate
 - Maximum frame rate in Full HD 1080p mode: 120 frame / s
- ◆ High dynamic range (HDR) function

Multiple exposure HDR

Digital overlap HDR

- ◆ Variable-speed shutter function (resolution 1H units)
- ◆ 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function

0 dB to 29.4 dB: Analog Gain 29.4 dB (step pitch 0.3 dB)

29.7 dB to 71.4 dB: Analog Gain 29.4 dB + Digital Gain 0.3 to 42 dB (step pitch 0.3 dB)

◆ Supports I/O switching

CMOS logic parallel SDR output

Low voltage LVDS (150 m Vp-p) serial (2 ch / 4 ch / 8 ch switching) DDR output CSI-2 serial data output (2 Lane / 4 Lane, RAW10 / RAW12 output)

◆ Recommended exit pupil distance: -30 mm to -∞



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Device Structure

◆ CMOS image sensor

◆ Image size

◆ Total number of pixels

◆ Number of effective pixels

◆ Number of active pixels

◆ Number of recommended recording pixels

◆ Unit cell size

◆ Optical black

♦ Dummy

◆ Package

Type 1/2.8

1945 (H) × 1109 (V) approx. 2.16 M pixels

1945 (H) × 1097 (V) approx. 2.13 M pixels

1937 (H) × 1097 (V) approx. 2.12 M pixels

1920 (H) × 1080 (V) approx. 2.07 M pixels

 $2.9 \mu m (H) \times 2.9 \mu m (V)$

Horizontal (H) direction: Front 0 pixel, rear 0 pixel

Vertical (V) direction: Front 10 pixels, rear 0 pixel

Horizontal (H) direction: Front 0 pixel, rear 3 pixels

Vertical (V) direction: Front 0 pixel, rear 0 pixel

110 pin LGA

Image Sensor Characteristics

(Tj = 60 °C)

Item		Value	Remarks	
Sensitivity (F5.6)	Тур.	10741 Digit	1/30s accumulation 12 bit converted value	
Saturation signal	Min.	3855 Digit	12 bit converted value	

Basic Drive Mode

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
Full HD 1080p	1920 (H) × 1080 (V) approx. 2.07 M pixels	120	LVDS CSI-2	10/12
HD 720p	1280 (H) × 720 (V) approx. 0.92 M pixels	120	LVDS CSI-2	10/12

